

December 2004

# **BAY71 Small Signal Diode**



DO-35 Color Band Denotes Cathode

## Absolute Maximum Ratings \* T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Unit	
V <sub>RRM</sub>	Maximum Repetitive Reverse Voltage	50	V	
I <sub>F(AV)</sub>	Average Rectified Forward Current	200	mA	
I <sub>FSM</sub>	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 4.0	A A	
T <sub>STG</sub>	Storage Temperature Range	-65 to +200	°C	
TJ	Operating Junction Temperature	175	°C	

\* These ratings are limiting values above which the serviceability of the diode may be impaired.

NOTES: 1) These ratings are based on a maximum junction temperature of 200 degrees C.

2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### **Thermal Characteristics**

Symbol	Parameter	Value	Unit	
PD	Power Dissipation	500	mW	
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient	300	°C/W	

Electrical Characteristics T<sub>C</sub> = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Max	Units
V <sub>R</sub>	Breakdown Voltage	$I_R = 5\mu A$	50		V
V <sub>F</sub>	Forward Voltage	$I_{F} = 0.1mA$ $I_{F} = 1.0mA$ $I_{F} = 10mA$ $I_{F} = 20mA$	0.48 0.57 0.69 0.76	0.56 0.69 0.88 1.0	V V V V
I <sub>R</sub>	Reverse Leakage	V <sub>R</sub> = 35V V <sub>R</sub> = 35V, T <sub>A</sub> = 125°C		100 100	nA μA
CT	Total Capacitance	V <sub>R</sub> = 0, f = 1.0MHz		2	pF
t <sub>rr</sub>	Reverse Recovery Time	$I_F = I_R = 10$ mA, $I_{rr} = 1.0$ mA, $R_L = 100\Omega$		4	ns
t <sub>fr</sub>	Forward Recovery Time	I <sub>F</sub> = 100mA		40	ns

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